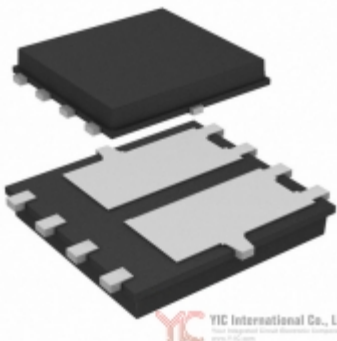
	<p>SI7904BDN-T1-E3</p>
	<p>Hersteller-Teilenummer: SI7904BDN-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2N-CH 20V 6A 1212-8</p> <p>Datenblätter:  SI7904BDN-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 7115 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7904BDN-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2N-CH 20V 6A 1212-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	7115 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	17.8W
Verpackung / Gehäuse	PowerPAK® 1212-8 Dual
Supplier Device-Gehäuse	PowerPAK® 1212-8 Dual
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	6A
Rds On (Max) @ Id, Vgs	30 mOhm @ 7.1A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	24nC @ 8V
Eingabekapazität (Ciss) (Max) @ Vds	860pF @ 10V
Verpackung	Tape & Reel (TR)































SI7904BDN-T1-E3 ist neu im Original. Suche SI7904BDN-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7904BDN-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7904BDN-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7904 VISHAY VISHAY QFN1212</p>	 <p>SI7904BDN-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 6A 1212-8</p>	 <p>SI7904BDN-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 20V 6A PPAK 1212-8</p>	 <p>SI7904DN-T1 VISHAY SI7904DN-T1 VISHAY</p>
 <p>SI7902EDN-T1-E3 VISHAY SI7902EDN-T1-E3 VISHAY</p>	 <p>SI7901EDN-T1-GE3 Vishay / Siliconix MOSFET 2P-CH 20V 4.3A 1212-8</p>	 <p>SI7904DN V SI7904DN V</p>	 <p>SI7901EDN-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 4.3A 1212-8</p>

heiße Teile

Mehr

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|---|---|---|---|--|
|  SI7892BDP-T1-GE3 |  SI7892DP |  SI7892DP-T1 |  SI7892DP-T1-E3 |  SI7892DP-T1-GE3 |
|  SI7898DP |  SI7898DP-T1-E3 |  SI7898DP-T1-E3 |  SI7898DP-T1-GE3 |  SI7898DP-T1-GE3 |
|  SI7900ADN |  SI7900AEDN |  SI7900AEDN-T1 |  SI7900AEDN-T1-E3 |  SI7900AEDN-T1-E3 |
|  SI7900AEDN-T1-GE3 |  SI7900AEDN-T1-GE3 |  SI7900EDN |  SI7900EDN-T1 |  SI7900EDN-T1-E3 |
|  SI7900EDN-T1-GE3 |  SI7901EDN-T1 |  SI7901EDN-T1-E3 |  SI7901EDN-T1-E3 |  SI7904BDN-T1-E3 |
|  SI7904BDN-T1-GE3 |  SI7904BDN-T1-GE3 |  SI7904DN |  SI7904DN-T1 |  SI7904DN-T1-E3 |
|  SI7904DN-T1-E3 |  SI7904DN-T1-GE3 |  SI7904DN-T1-GE3 |  SI7905DN-T1-GE3 |  SI7905DN-T1-GE3 |
|  SI7909DN-T1-E3 |  SI7909DN-T1-E3 |  SI7909DN-T1-GE3 |  SI7909DN-T1-GE3 |  SI7911DN |
|  SI7911DN-T1-E3 |  SI7911DN-T1-E3 |  SI7911DN-T1-GE3 |  SI7911DN-T1-GE3 |  SI7913DN-T1-E3 |
|  SI7913DN-T1-E3 |  SI7913DN-T1-GE3 |  SI7913DN-T1-GE3 |  SI7922DN-T1-E3 |  SI7922DN-T1-E3 |

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